

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	10066	257/635,642,750,758-760,762,773,774.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/11/10 12:07
L2	404	1 and (((inter near level) interlevel) ILD) with (dielectric adj (film layer)))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/11/10 12:49
L3	1	2 and (different near morphology)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/11/10 12:49
L4	153	2 and ((low near k) (organosilicon near glass\$2) SiCOH)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/11/10 12:13
L5	357	2 and thick\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/11/10 12:17
L6	1	2 and (thick\$4 with (greater larger) near ("1000" "12000"))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/11/10 12:51
L7	138	4 and thick\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/11/10 12:17
L8	4884	(((inter near level) interlevel) ILD) with (dielectric adj (film layer)))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/11/10 14:02
L9	3	8 and (different near morphology)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/11/10 12:49

L10	0	8 and (dielectric with thick\$4 with (greater larger) near ("1000" "12000"))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/11/10 13:10
L11	216	8 and (dielectric with thick\$4 with ("1000" "12000"))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/11/10 13:35
L12	0	8 and (dielectric with thick\$4 with ("1000" near2 "2000") with ("12000" near2 "20000"))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/11/10 13:34
L13	5	8 and (((first lower bottom) near dielectric) with ((second upper top) near dielectric)with thick\$4 with ("1000" "12000" "2000" "20000"))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/11/10 13:46
L14	5	8 and (((first lower bottom) near dielectric) with ((second upper top) near dielectric) with thick\$4 with ("1000" "12000" "2000" "20000"))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/11/10 13:47
L15	49	11 and (((first lower bottom) near dielectric) with ((second upper top) near dielectric))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/11/10 13:47
L16	1	(((inter near level) interlevel) ILD) AND (dielectric adj (film layer)) AND (similar near chemical near composition) AND (different near morphology).CLM.	US-PGPUB; USPAT	OR	ON	2005/11/10 14:05
L17	0	(((inter near level) interlevel) ILD) AND (dielectric adj (film layer)) AND thick\$4 AND (range near2 ("1000" near2 "2000")) AND (range near2 ("12000" near2 "20000")).CLM.	US-PGPUB; USPAT	OR	ON	2005/11/10 14:09
L18	0	(((inter near level) interlevel) ILD) AND (dielectric adj (film layer)) AND thick\$4 AND ("1000" near2 "2000") AND ("12000" near2 "20000").CLM.	US-PGPUB; USPAT	OR	ON	2005/11/10 14:08
L19	0	(((inter near level) interlevel) ILD) AND (dielectric adj (film layer)) AND thick\$4 AND range AND ("1000" near2 "2000") AND ("12000" near2 "20000").CLM.	US-PGPUB; USPAT	OR	ON	2005/11/10 14:09

L20	0	((inter near level) interlevel) ILD) AND (dielectric adj (film layer)) AND thick\$4 AND (range with ("1000" near2 "2000")) AND (range with ("12000" near2 "20000")).CLM.	US-PGPUB; USPAT	OR	ON	2005/11/10 14:09
L21	4	((inter near level) interlevel) ILD) AND (dielectric adj (film layer)) AND thick\$4 AND (range near2 ("1000" "2000")) AND (range near2 ("12000" "20000")).CLM.	US-PGPUB; USPAT	OR	ON	2005/11/10 14:10